Features

- Floating channel designed for bootstrap operation
- Fully operational to +600 V
- Tolerant to negative transient voltage, dV/dt immune
- Gate drive supply range from 10 V to 20 V
- Undervoltage lockout for both channels
- 3.3 V and 5 V input logic compatible
- Matched propagation delay for both channels
- Logic and power ground +/- 5 V offset
- Lower di/dt gate driver for better noise immunity
- Output source/sink current capability (typical) 1.9 A /2.3 A
- Leadfree, RoHS compliant
- Automotive qualified*

Typical Applications

- Piezo/ common rail Injection
- Starter/Alternator
- Electric Power Steering
- Fan and compressor

Product Summary

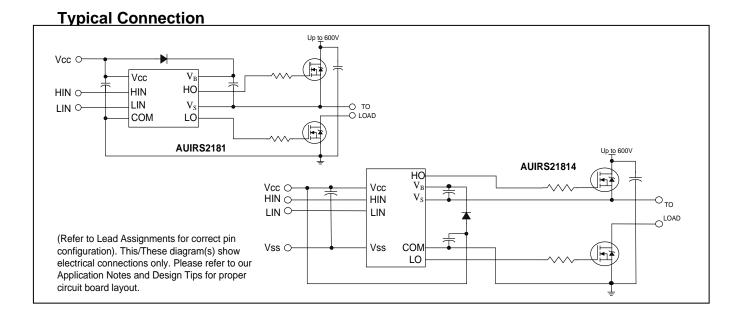
Topology	High and Low Side Driver
V _{OFFSET}	≤ 600 V
V _{OUT}	10 V – 20 V
I _{o+} & I _{o-} (typical)	1.9 A &2.3 A
t _{ON} & t _{OFF} (typical)	160 ns & 200 ns

Package Options



8-Lead SOIC AUIRS2181S

14-Lead SOIC Narrow Body AUIRS21814S





Ordering Information

Deers Devi Nevel en		Standard Pack		
Base Part Number	Package Type	Form		Complete Part Number
	SOIC8	Tube/Bulk	95	AUIRS2181S
AUIRS2181S	30108	Tape and Reel	2500	AUIRS2181STR
	SOIC14N	Tube/Bulk	55	AUIRS21814S
AUIRS21814S	SOIC14N	Tape and Reel	2500	AUIRS21814STR



Description

The AUIRS2181(4)(S) are high voltage, high speed power MOSFET and IGBT drivers with independent high and low-side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3 V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high-side configuration which operates up to 600 V.

Part	Input Logic	Cross- Conduction Prevention logic	Dead-Time	Ground Pins	Ton/Toff
2181				COM	160/200 pc
21814	HIN/LIN	no	none	V _{SS} /COM	160/200 ns
2183			Internal 500ns	COM	160/200 pa
21834	HIN/LIN	yes	Programmable 0.4 – 5 us	V _{SS} /COM	160/200 ns
2184			Internal 500ns	COM	C00/220 mg
21844	IN/SD	yes	Programmable 0.4 – 5 us	V _{SS} /COM	600/230 ns

Feature Comparison: AUIRS2181/AUIRS2183/AUIRS2184



Absolute Maximum Ratings

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM lead. Stresses beyond those listed under " Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the "Recommended Operating Conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature (T_A) is 25°C, unless otherwise specified.

Symbol	Definition		Min	Max	Units
V _B	High-side floating absolute voltage		-0.3	625	
Vs	High-side floating supply offset voltage	V _B - 25	V _B +0.3		
V _{HO}	High-side floating output voltage	V _S - 0.3	V _B +0.3		
V _{CC}	Low-side and logic fixed supply voltage	-0.3	20 (†)	V	
V_{LO}	Low-side output voltage	-0.3	$V_{CC} + 0.3$		
V _{IN}	Logic input voltage (HIN &LIN)	V _{SS} -0.3	$V_{CC} + 0.3$		
V _{SS}	Logic ground (AUIRS21814(S) only)	V _{CC} - 20	$V_{CC} + 0.3$		
dV _S /dt	Allowable offset supply voltage transient		—	50	V/ns
P _D	Package power dissipation @ TA ≤ 25°C	(8 lead SOIC)	—	0.625	W
гD	Tackage power dissipation @ TA = 25 C	(14 lead SOIC)	_	1.0	vv
Dth	Thermel resistance in action to embient	(8 lead SOIC)	—	200	80 MM
Rth_JA	Thermal resistance, junction to ambient	—	120	°C/W	
TJ	Junction temperature	_	150		
Τs	Storage temperature	-50	150	°C	
TL	Lead temperature (soldering, 10 seconds)		_	300	

† All supplies are fully tested at 25 V and an internal 20 V clamp exists for each supply.

Recommended Operating Conditions

The input/output logic timing diagram is shown in figure 1. For proper operation the device should be used within the recommended conditions. The V_S and V_{SS} offset rating are tested with all supplies biased at 15 V differential.

Symbol	Definition	Min	Max	Units
VB	High-side floating supply absolute voltage	V _s +10	V _S +20	
Vs	High-side floating supply offset voltage	(††)	600	
V _{HO}	High-side floating output voltage	Vs	V _B	
V _{CC}	Low-side and logic fixed supply voltage	10	20	V
V _{LO}	Low-side output voltage	0	V _{cc}	V
V _{IN}	Logic input voltage	V _{SS}	V _{cc}	
DT	Programmable deadtime pin voltage	V _{SS}	V _{cc}	
V _{SS}	Logic ground	-5	5	
T _A	Ambient temperature	-40	125	°C

^{††} Logic operational for V_S of -5 V to +600 V. Logic state held for V_S of -5 V to $-V_{BS}$. (Please refer to the Design Tip DT97-3 for more details).



Dynamic Electrical Characteristics

Unless otherwise noted, these specifications apply for an operating junction temperature range of -40°C \leq Tj \leq 125°C with bias conditions of V_{BIAS} (V_{CC}, V_{BS}) = 15 V, V_{SS} = COM, C_L = 1000 pF.

Symbol	Definition	Min	Тур	Max	Units	Test Conditions
t _{on}	Turn-on propagation delay	—	160	270		$V_{\rm S} = 0 \ V$
t _{off}	Turn-off propagation delay	_	200	330		$V_{\rm S}$ = 0 V or 600 V
MT	Delay matching, HS & LS turn-on/off	—		35	ns	
t _r	Turn-on rise time	—	15	60		
t _f	Turn-off fall time	_	15	35		$V_{S} = 0 V$

Static Electrical Characteristics

Unless otherwise noted, these specifications apply for an operating junction temperature range of -40°C \leq Tj \leq 125°C with bias conditions of V_{BIAS} (V_{CC}, V_{BS}) = 15 V, V_{SS} = COM. The V_{IL}, V_{IH} and I_{IN} parameters are referenced to V_{SS}/COM and are applicable to the respective input leads: HIN and LIN. The V_O, I_O and Ron parameters are referenced to COM and are applicable to the respective output leads: HO and LO.

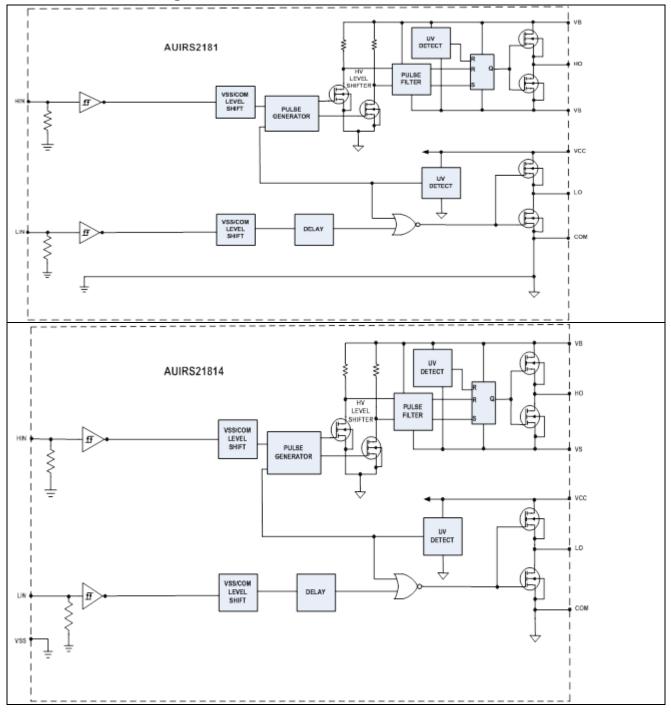
Symbol	Definition	Min	Тур	Max	Units	Test Conditions
V _{IH}	Logic "1" input voltage	2.5				$V_{CC} = 10 \text{ V to } 20 \text{ V}$
V _{IL}	Logic "0" input voltage	—		0.8	v	V_{CC} = 10 V to 20 V
V _{OH}	High level output voltage, V_{BIAS} - V_{O}	—		1.4	v	$I_0 = 0 \text{ mA}$
V _{OL}	Low level output voltage, Vo		—	0.2		I _O = 20 mA
I _{LK}	Offset supply leakage current		—	50		$V_{\rm B} = V_{\rm S} = 600 \ {\rm V}$
I _{QBS}	Quiescent V _{BS} supply current	15	60	150		$V_{IN} = 0 V \text{ or } 5 V$
l _{QCC}	Quiescent V _{CC} supply current	15	120	240	μA	$v_{\rm IN} = 0$ v or 5 v
I _{IN+}	Logic "1" input bias current	—	25	60		$V_{IN} = 5 V$
I _{IN-}	Logic "0" input bias current	—	—	5.0		$V_{IN} = 0 V$
V _{CCUV+} V _{BSUV+}	V_{CC} and V_{BS} supply undervoltage positive going threshold	8.0	8.9	9.8		
V _{CCUV-} V _{BSUV-}	V_{CC} and V_{BS} supply undervoltage negative going threshold	7.4	8.2	9.0	V	
V _{CCUVH} V _{BSUVH}	V_{CC} and V_{BS} supply undervoltage Hysteresis	0.3	0.7			
I _{O25+} ^(†)	Output high short circuit pulsed current	1.4	1.9	_		V _O = 0V, PW ≤ 10us, T _J = 25°C
I ₀₂₅ - ^(†)	Output low short circuit pulsed current	1.8	2.3	_	A	V _O = 15V, PW ≤ 10us, T _J = 25°C
$I_{O+}^{(\dagger)(\dagger\dagger)}$	Output high short circuit pulsed current	1.2	—			$V_{O} = 0 V,$ PW $\leq 10 us$
I _{O-} ^{(†)(††)}	Output low short circuit pulsed current	1.5	_	_		V _O = 15 V, PW ≤ 10 us

(†) Guaranteed by design

(††) I_{O+} and I_{O-} decrease with rising temperature



Functional Block Diagrams: AUIRS2181, AUIRS21814





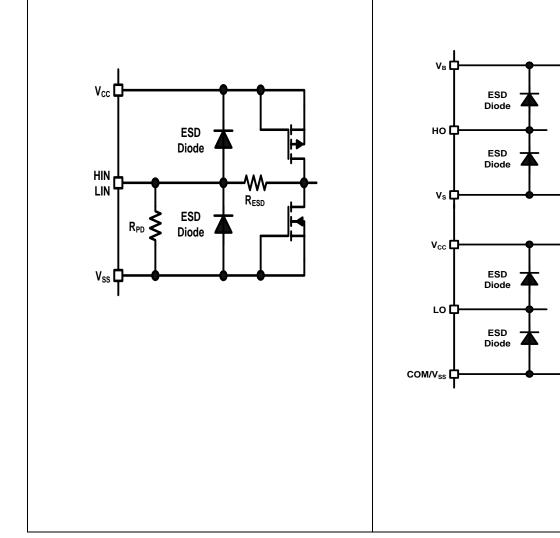
20V

600V **Z**

20V

Z

Input/Output Pin Equivalent Circuit Diagrams: AUIRS2181S



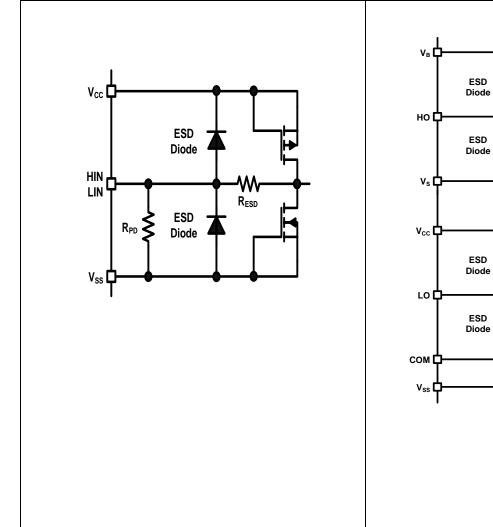


20V

600V

20V 🛣 20V

Input/Output Pin Equivalent Circuit Diagrams: AUIRS21814S

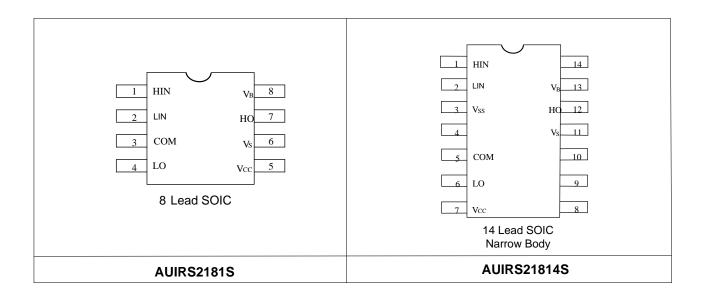




Lead Definitions: AUIRS2181(4)S

Symbol	Description
HIN	Logic input for high-side gate driver output (HO), in phase
LIN	Logic input for low-side driver output (LO), in phase
V _{SS}	Logic ground (AUIRS21814 only)
VB	High-side floating supply
НО	High-side gate drive output
Vs	High-side floating supply return
V _{CC}	Low-side and logic fixed supply
LO	Low-side gate drive output
COM	Low-side return

Lead Assignments: AUIRS2181(4)S





Application Information and Additional Details

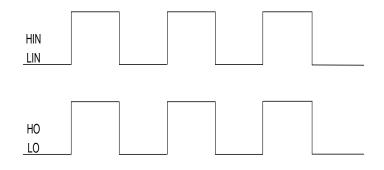


Figure 1. Input/Output Timing Diagram

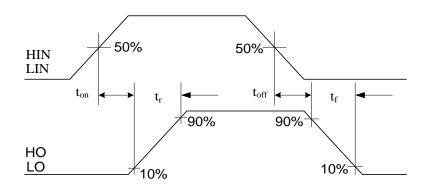
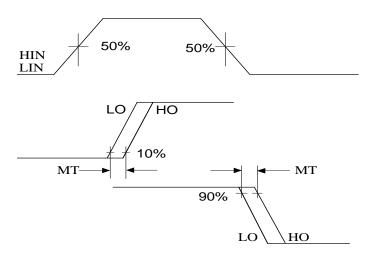
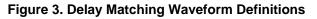


Figure 2. Switching Time Waveform Definitions







Parameter Trends vs. Temperature and vs. Supply Voltage

Figures of this chapter provide information on the experimental performance of the AUIRS2181(4)S HVIC. The line plotted in each figure is generated from actual lab data.

A large number of individual samples were tested at three temperatures (-40 °C, 25 °C, and 125 °C) in order to generate the experimental curve. The line consists of three data points (one data point at each of the tested temperatures) that have been connected together to illustrate the understood trend. The individual data points on the Typ. curve were determined by calculating the averaged experimental value of the parameter (for a given temperature).

A different set of individual samples was used to generate curves of parameter trends vs. supply voltage.

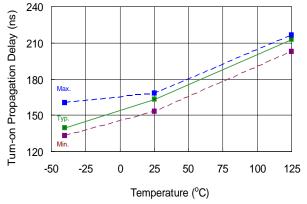


Figure 1A. Turn-On Propagation Delay vs. Temperature

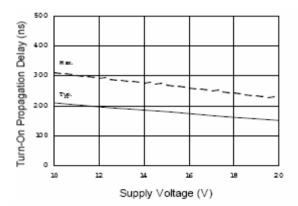


Figure 1B. Turn-On Propagation Delay vs. Supply Voltage

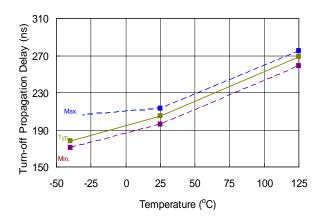


Figure 2A. Turn-Off Propagation Delay vs. Temperature

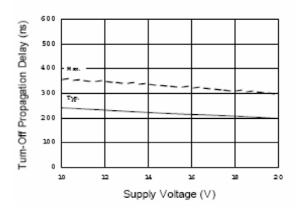


Figure 2B. Turn-Off Propagation Delay vs. Supply Voltage



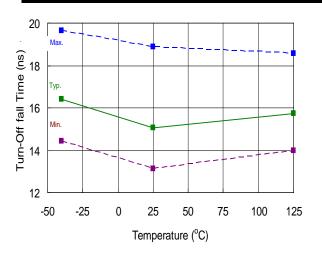


Figure 3A. Turn-Off Fall Time vs. Temperature

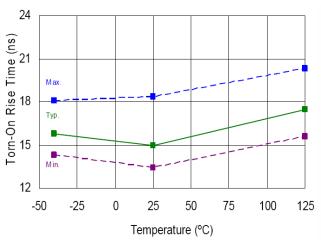


Figure 4. Turn-On Rise Time vs. Temperature

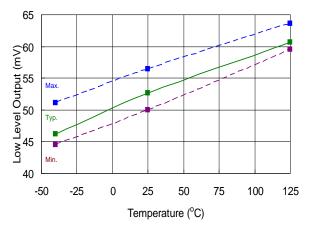


Figure 6. Low Level Output vs. Temperature

AUIRS2181(4)S

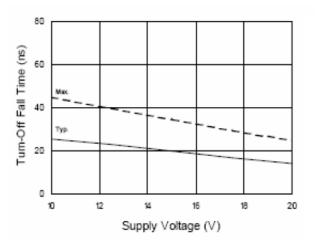


Figure 3B. Turn-Off Fall Time vs. Supply Voltage

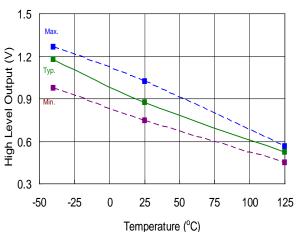


Figure 5. High Level Output Voltage vs. Temperature (Io = 0mA)

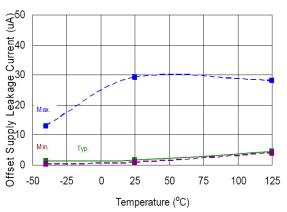


Figure 7. Offset Supply Leakage Current vs. Temperature



250 V_{BS} Supply Current (µA) 200 Max 150 100 Гур 50 Min 0 75 -50 -25 25 125 50 100 0 Temperature (°C)

Figure 8A V_{BS} Supply Current vs. Temperature

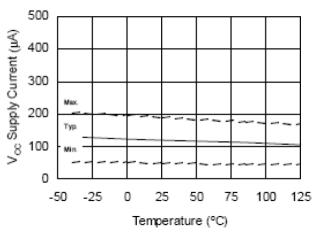
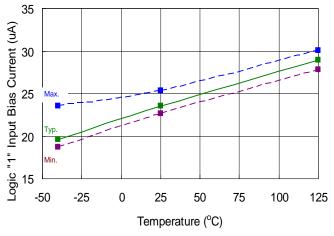


Figure 9A V_{CC} Supply Current vs Temperature





13

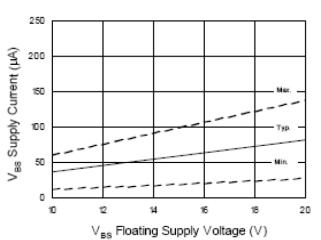


Figure 8B V_{BS} Supply Current vs. V_{BS} Floating Supply Voltage

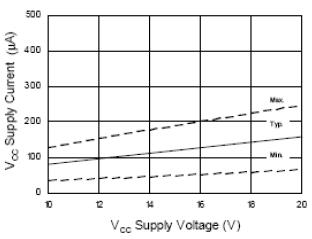


Figure 9B V_{CC} Supply Current vs. V_{CC} Supply Voltage

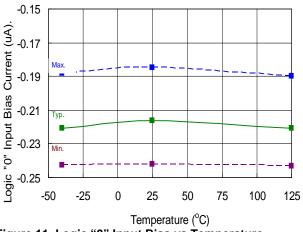


Figure 11. Logic "0" Input Bias vs Temperature

AUIRS2181(4)S



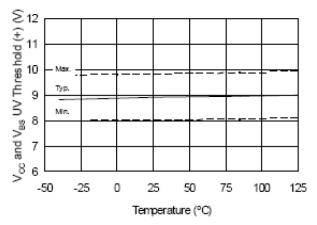


Figure 12. V_{CC} and V_{BS} Undervoltage Threshold(+) vs Temperature

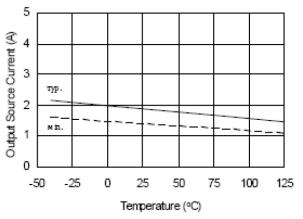


Figure 14A. Output Source Current vs Temperature

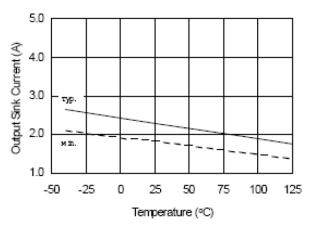


Figure 15A. Output Sink Current vs Temperature

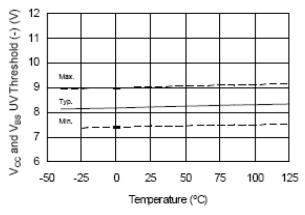


Figure 13. V_{CC} and V_{BS} Undervoltage Threshold(-) vs Temperature

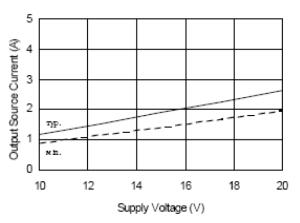


Figure 14B. Output Source Current vs Supply Voltage

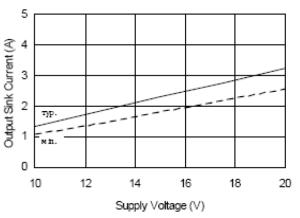


Figure 15B. Output Sink Current vs Supply Voltage

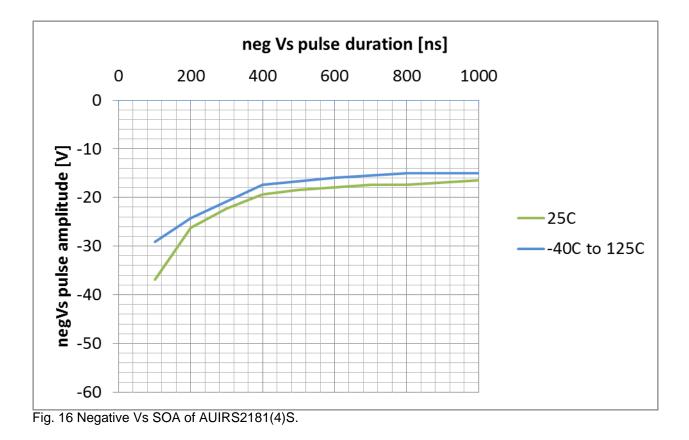


Negative Vs Safety Operating Area (negVs SOA)

There could be conditions in which Vs node falls below (i.e. negative) VSS/COM nodes (e.g. because of wrong system layout). This condition should be avoided because it could bring to uncontrolled behavior of the driver.

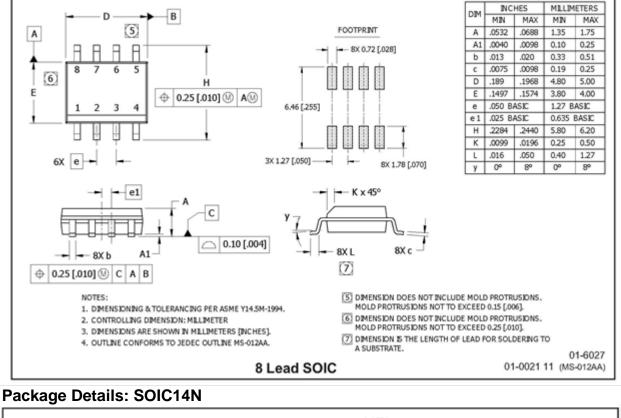
The negVs SOA identifies the energy of negative Vs pulses at which the driver can withstand; pulse energy is identified as the product of pulse duration by its amplitude. Fig. 16 shows the negVs SOA of AUIRS2181(4)S at both ambient and over temperature conditions. Test conditions were VCC=VBS=15V referenced to VSS=COM.

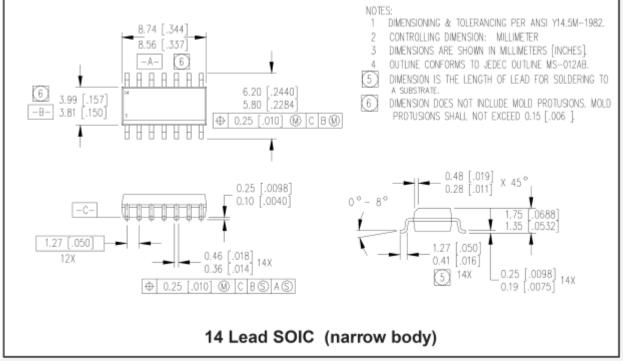
Even though the AUIRS2181(4)S has been designed and tested to handle these negative VS transient conditions, it is highly recommended that the circuit designer always limit the negative VS transients as much as possible by careful PCB layout and component use.



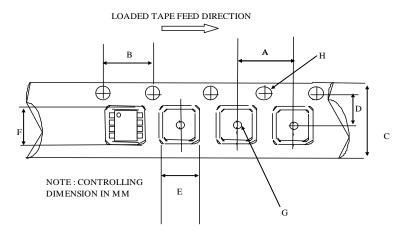


Package Details: SOIC8



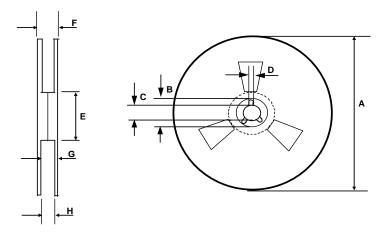


Tape and Reel Details: SOIC8



CARRIER TAPE DIMENSION FOR 8SOICN

	Me	tric	Imp	erial
Code	Min	Max	Min	Max
A	7.90	8.10	0.311	0.318
В	3.90	4.10	0.153	0.161
С	11.70	12.30	0.46	0.484
D	5.45	5.55	0.214	0.218
E	6.30	6.50	0.248	0.255
F	5.10	5.30	0.200	0.208
G	1.50	n/a	0.059	n/a
Н	1.50	1.60	0.059	0.062

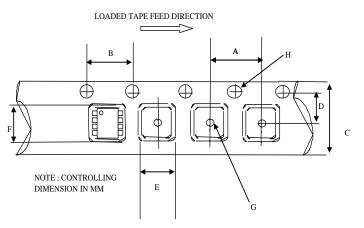


REEL DIMENSIONS FOR 8SOICN

	Me	tric	Imp	erial
Code	Min	Max	Min	Max
A	329.60	330.25	12.976	13.001
В	20.95	21.45	0.824	0.844
С	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	18.40	n/a	0.724
G	14.50	17.10	0.570	0.673
Н	12.40	14.40	0.488	0.566

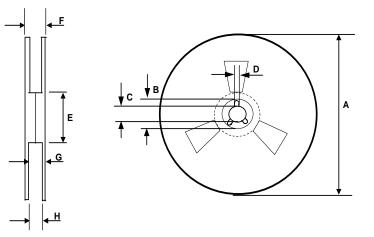


Tape and Reel Details: SOIC14N



CARRIER TAPE DIMENSION FOR 14SOICN

	Me	etric	Imp	erial
Code	Min	Max	Min	Max
A	7.90	8.10	0.311	0.318
В	3.90	4.10	0.153	0.161
С	15.70	16.30	0.618	0.641
D	7.40	7.60	0.291	0.299
E	6.40	6.60	0.252	0.260
F	9.40	9.60	0.370	0.378
G H	1.50	n/a	0.059	n/a
Н	1.50	1.60	0.059	0.062



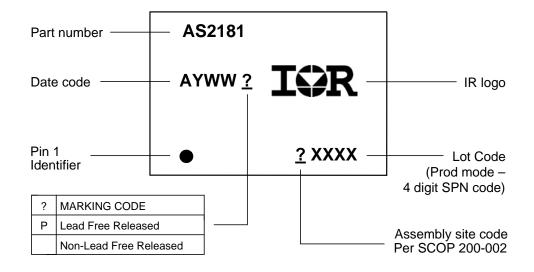
REEL DIMENSIONS FOR 14SOICN

	Metric		Imp	erial
Code	Min	Max	Min	Max
A	329.60	330.25	12.976	13.001
В	20.95	21.45	0.824	0.844
С	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	22.40	n/a	0.881
G	18.50	21.10	0.728	0.830
Н	16.40	18.40	0.645	0.724

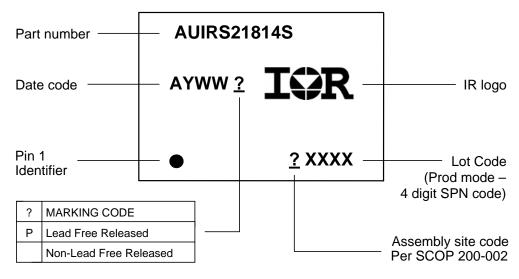


Part Marking Information

SOIC8:



SOIC14N:





Qualification Information[†]

Qualification Level		Automotive (per AEC-Q100++)	
		Comments: This family of ICs has passed an Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.	
Moisture Sensitivity Level		SOIC8	MSL3 ^{ttt} 260°C (per IPC/JEDEC J-STD-020)
		SOIC14N	MSL3 ^{†††} 260°C (per IPC/JEDEC J-STD-020)
ESD	Machine Model	Class M2 (Pass +/-150V) (per AEC-Q100-003)	
	Human Body Model	Class H1B (Pass +/-1000V)	
		(per AEC-Q100-002)	
	Charged Device Model	Class C4 (Pass +/-1000V)	
		(per AEC-Q100-011)	
IC Latch-Up Test		Class II, Level A ^{tttt}	
		(per AEC-Q100-004)	
RoHS Compliant		Yes	

† Qualification standards can be found at International Rectifier's web site http://www.irf.com/

tt Exceptions to AEC-Q100 requirements are noted in the qualification report.

- +++ Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.
- †††† HIN, LIN Class II Level B at 80mA per JESD78.



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Revision History

Date	Comment		
04/29/08	Draft		
5/6/08	Converted to new automotive format		
9/30/08	Reviewed and updated various missing information		
10/01/08	Inserted Input/Output Pin Equivalent Circuit Diagram		
Feb, 10 th , 2009	Typ application list and other minor changes		
Feb. 11, 2009	Removed PDIP package versions from datasheet		
Aug. 4, 2009	Updated qualification information, characterization curves		
Aug. 11, 2009	Updated plot, removed characterization graphs, changes package type info		
Aug. 13, 2009	Updated VIH/VIL graphs		
Sep 23 rd , 2009	Typ appl. Section update; Rearranged graphs with temperature and supply characteristic, updated marking detail with p/n; added ESD passing voltage; update LU test passing current from 40mA to 80mA.		
Dec. 16, 09	Changed Iqcc/Iqbs min to 15uA; added Important Notice page; changed ton typ=160ns; toff typ=200ns; tr typ=15ns; tf typ=15ns		
Feb. 24, 2010	Page 6: Added I ₀₂₅₊ and I ₀₂₅₋ specification and the notes		
Jul. 27, 2010	clamp diode values changed from 25V into 20V (in-out pin eq. circ. diagrams)		
Mar 07, 2012	Input zener clamp note deleted in recommended op cond		
Sept. 30 th , 2013	Added negVs SOA		
Oct. 04 th , 2013	Adapted to new format		
Jan. 10, 2014	Updated datasheet to display respective page number on bottom left corner of every page		

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